TOSHIBA Diode Silicon Epitaxial Planar Type

# **1SS382**

### **Ultra High Speed Switching Application**

• Small package

• Composed of 2 independent diodes.

• Low forward voltage :  $V_{F(3)} = 0.92V$  (typ.)

• Fast reverse recovery time:  $T_{rr} = 1.6ns$  (typ.)

### **Maximum Ratings (Ta = 25°C)**

Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse Voltage	$V_{RM}$	85	V
Reverse voltage	$V_{R}$	80	V
Maximum (peak) forward current	I <sub>FM</sub>	300 *	mA
Average forward current	Io	100 *	mA
Surge current (10ms)	I <sub>FSM</sub>	2	Α
Power dissipation	Р	100 *	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

<sup>\*:</sup> Unit rating. Total rating = unit rating × 1.5

# 1. ANODE 1 2. ANODE 2 3. CATHODE 2 4. CATHODE 1 JEDEC — EIAJ — TOSHIBA 1-2U1A

Weight: 0.006g

### **Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V <sub>F (1)</sub>	_	I <sub>F</sub> = 1mA	1	0.61	-	V
	V <sub>F (2)</sub>	_	I <sub>F</sub> = 10mA		0.74	-	V
	V <sub>F (3)</sub>	_	I <sub>F</sub> = 100mA	-	0.92	1.20	V
Reverse current	I <sub>R (1)</sub>	_	V <sub>R</sub> = 30V		1	0.1	μΑ
	I <sub>R (2)</sub>	_	V <sub>R</sub> = 80V	-	-	0.5	μA
Total capacitance	СТ	_	VR = 0, f = 1MHz	_	0.9	2.0	pF
Reverse recovery time	trr	_	IF = 10mA, Fig.1	_	1.6	4.0	ns

### **Pin Assignment (Top View)**



## Marking

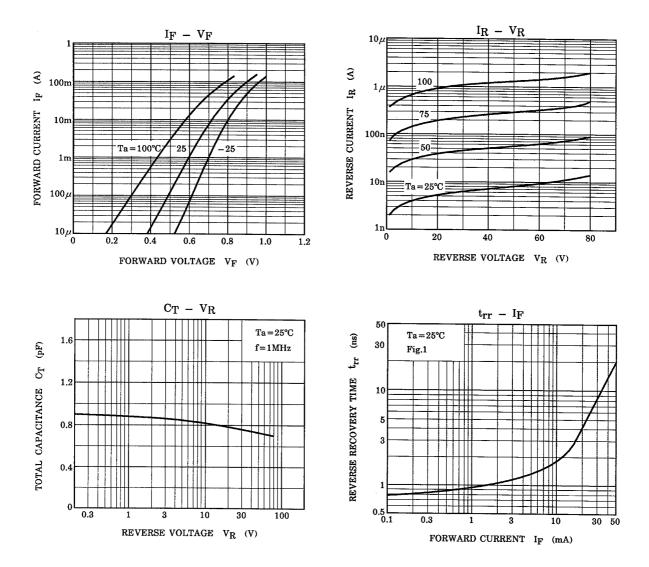
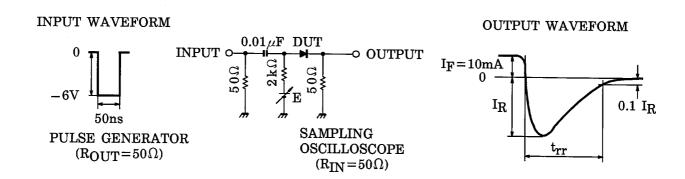


Fig.1 Reverse Recovery Time (t<sub>rr</sub>) Test Circuit



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